PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2 EPAS ID: PAT6543416

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
KUO-CHENG CHING	05/23/2019
SHI NING JU	05/23/2019
KUAN-LUN CHENG	05/23/2019
CHIH-HAO WANG	05/23/2019

RECEIVING PARTY DATA

Name:	TAIWAN SEMICONDUCTOR MANUFACTURING CO., LTD.	
Street Address:	8, LI-HSIN RD. 6	
Internal Address:	HSINCHU SCIENCE PARK	
City:	HSINCHU	
State/Country:	TAIWAN	
Postal Code:	300-78	

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	17171865

CORRESPONDENCE DATA

Fax Number: (214)200-0853

Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.

Phone: 214-651-5000

Email: ipdocketing@haynesboone.com

Correspondent Name: HAYNES AND BOONE, LLP (24061) IP SECTION

Address Line 1: 2323 VICTORY AVENUE

Address Line 2: SUITE 700

Address Line 4: DALLAS, TEXAS 75219

ATTORNEY DOCKET NUMBER:	2018-0030US02/24061.3724U
NAME OF SUBMITTER:	LINDA INGRAM
SIGNATURE:	/Linda Ingram/
DATE SIGNED:	02/09/2021

Total Attachments: 2

PATENT REEL: 055203 FRAME: 0871 source=3724US02_Assignment#page1.tif source=3724US02_Assignment#page2.tif

PATENT REEL: 055203 FRAME: 0872

Docket No.: P20180030US00/24061.3724US01

Customer No.: 000042717

ASSIGNMENT

WHEREAS, we,

(1)	Kuo-Cheng Ching	of	Hsinchu County, Republic of China
(2)	Shi Ning Ju	of	Hsinchu City, Republic of China
(3)	Kuan-Lun Cheng	of	Hsin-Chu, Republic of China
(4)	Chih-Hao Wang	of	Hsinchu County, Republic of China

have invented certain improvements in

FIN-LIKE FIELD EFFECT TRANSISTOR PATTERNING METHODS FOR ACHIEVING FIN WIDTH UNIFORMITY

for which we have executed an application for Letters Patent of the United States of America,

of even date filed herewith; and filed on April 18, 2019, and assigned application number 16/387,889; and

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Co., Ltd., ("TSMC"), 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78, Republic of China. is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

4837-9616-6023.v.1 - 1 -

Docket No.: P20180030US00/24061.3724US01

Customer No.: 000042717

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional, continuing, and reissue applications, make all rightful declarations and/or oaths and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name:	Kuo-Cheng Ching	
Residence Address:	5F., No. 8-3, Guangming 9th Re Zhubei City, Hsinchu County 3	
Dated: 1019/5/	\}	Inventor Signature
Inventor Name:	Shi Ning Ju	
Residence Address:	10F., No. 306, Ln. 1050, Mingh Hsinchu City 300, Taiwan (R.O	
Dated: 20/9, 1	<u> </u>	SHI WING TU Inventor Signature
Inventor Name:	Kuan-Lun Cheng	
Residence Address:	13F-3, No 152, Jhong-Yang Rd Hsin-Chu, Taiwan (R.O.C.)	
Dated: 2019/	723	Kuan-Ru Chey Inventor Signature
Inventor Name:	Chih-Hao Wang	
Residence Address:	No. 9, Aly. 22, Ln. 80, Songcui Hsinchu County 308, Taiwan	Rd., Baoshan Township,
Dated: 2019/5	<u> </u>	Chih - Hao Wang Inventor Signature

4837-9616-6023 v.1

RECORDED: 02/09/2021

- 2 -